Characteristics STTH1002C-Y

1 **Characteristics**

Table 2. Absolute ratings (limiting values, per diode)

Symbol	Parameter	Value	Unit		
V_{RRM}	Repetitive peak reverse voltage			200	V
1	Forward rms current	D ² PAK	20	А	
I _F (RMS)	Forward fins current		DPAK		10
	Avarage forward current $\delta = 0.5$	T _c = 155 °C	Per diode	5	Α
		T _c = 150 °C	Per device	10	
^I F(AV)		T _c = 135 °C	Per diode	8	A
		T _c = 125 °C	Per device	16	ļ
I _{FSM}	Surge non repetitive forward current $t_p = 10 \text{ ms sinusoidal}$			50	Α
T _{stg}	Storage temperature range			-65 to + 175	°C
Tj	Operating junction temperature range			-40 to + 175	°C

Table 3. Thermal parameters

Symbol	Parameter	Value (max)	Unit
B	Junction to case Per diode	4.0	
R _{th(j-c)}	Per device	2.5	°C/W
R _{th(j-c)}	Coupling	1.0	

When the diodes 1 and 2 are used simultaneously: ΔT_i (diode1) = P(diode1) x $R_{th(i-c)}$ (per diode) + P(diode2) x $R_{th(c)}$

Table 4. Static electrical characteristics (per diode)

Symbol	Parameter	Test conditions		Min.	Тур.	Max.	Unit
I _R ⁽¹⁾	Reverse leakage current	T _j = 25 °C	$V_R = V_{RRM}$			5	μA
		T _j = 125 °C			3	40	μΛ
V _F ⁽²⁾	Forward voltage drop	T _j = 25 °C	I _F = 5 A			1.1	V
		T _j = 25 °C	I _F = 10 A			1.25	
		T _j = 150 °C	I _F = 5 A		0.78	0.89	V
		T _j = 150 °C	I _F = 10 A			1.05	

^{1.} Pulse test: t_p = 5 ms, δ < 2 %

To evaluate the conduction losses use the following equation: P = 0.73 x $I_{F(AV)}$ + 0.032 $I_{F}^{2}_{(RMS)}$

$$P = 0.73 \times I_{F(AV)} + 0.032 I_{F^2(RMS)}$$

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^{2.} Pulse test: t_p = 380 μ s, δ < 2 %

STTH1002C-Y Characteristics

Table 5. Dynamic electrical characteristics

Symbol	Parameter	Test conditions		Min.	Тур.	Max.	Unit
t _{rr}	Reverse recovery time	1 _j = 25 °C	$I_F = 1 \text{ A V}_R = 30 \text{ V}$ $dI_F/dt = 100 \text{ A/}\mu\text{s}$		20	25	ns
I _{RM}	Reverse recovery current	T _j = 125 °C	$I_F = 5 \text{ A}$ $V_R = 160 \text{ V}$ $dI_F/dt = 200 \text{ A/}\mu\text{s}$		5.9	7.6	Α
t _{fr}	Forward recovery time	T _j = 25 °C	$I_F = 5 \text{ A}$ $dI_F/dt = 100 \text{ A/}\mu\text{s}$ $V_{FR} = 1.1 \text{ x } V_{Fmax}$			110	ns
V _{FP}	Forward recovery voltage	T _j = 25 °C	$I_F = 5 \text{ A}$ $dI_F/dt = 100 \text{ A/}\mu\text{s}$		2.4		V

Characteristics STTH1002C-Y

Figure 1. Peak current versus duty cycle (per diode)

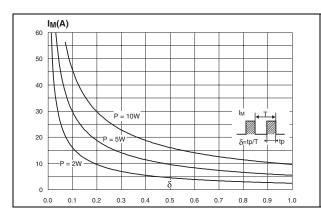


Figure 2. Forward voltage drop versus forward current (typical values, per diode)

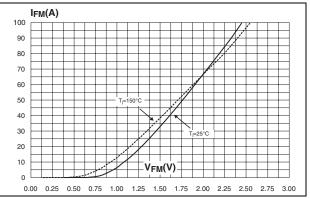


Figure 3. Forward voltage drop versus forward current (maximum values, per diode)

IFM(A)

100

90

80

70

60

50

40

30

20

10

0.000 0.25 0.50 0.75 1.00 1.25 1.50 1.75 2.00 2.25 2.50 2.75 3.00

Figure 4. Relative variation of thermal impedance junction to case versus pulse duration

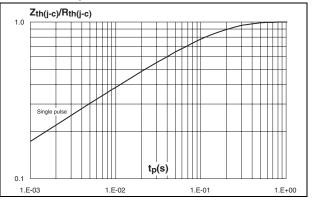


Figure 5. Junction capacitance versus reverse voltage applied (typical values, per diode)

V_R(V)

C(pF)

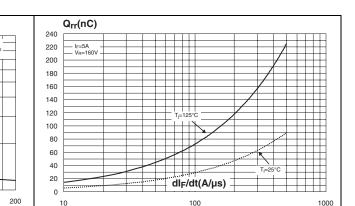


Figure 6. Reverse recovery charges versus dl_F/dt (typical values, per diode)

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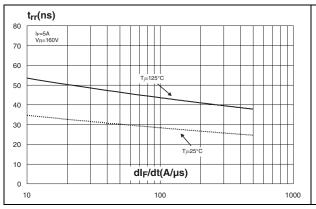
10

F=1MHz

STTH1002C-Y Characteristics

Figure 7. Reverse recovery time versus dl_F/dt Figure 8. (typical values, per diode)

Peak reverse recovery current versus dl_F/dt (typical values, per diode)



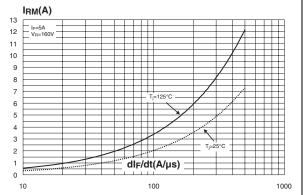
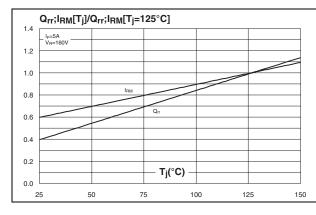


Figure 9. Dynamic parameters versus junction temperature

Figure 10. Thermal resistance junction to ambient versus copper surface under tab for D²PAK



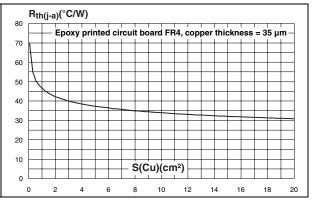
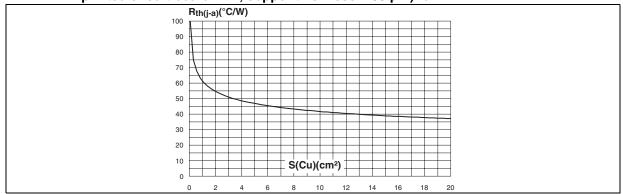


Figure 11. Thermal resistance junction to ambient versus copper surface under tab (Epoxy printed circuit board FR4, copper thickness = 35 µm) for DPAK

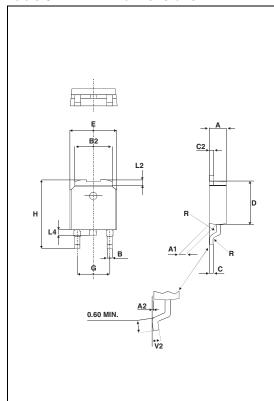


2 Package mechanical data

- Epoxy meets UL94, V0
- Cooling method: by conduction (method C)

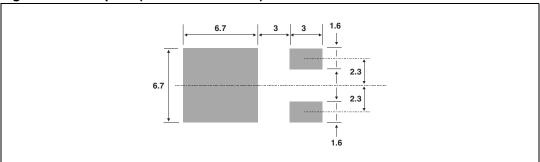
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Table 6. DPAK dimensions



	Dimensions					
Ref.	Millim	neters	Inches			
	Min.	Max.	Min.	Max.		
Α	2.20	2.40	0.086	0.094		
A1	0.90	1.10	0.035	0.043		
A2	0.03	0.23	0.001	0.009		
В	0.64	0.90	0.025	0.035		
B2	5.20	5.40	0.204	0.212		
С	0.45	0.60	0.017	0.023		
C2	0.48	0.60	0.018	0.023		
D	6.00	6.20	0.236	0.244		
Е	6.40	6.60	0.251	0.259		
G	4.40	4.60	0.173	0.181		
Н	9.35	10.10	0.368	0.397		
L2	0.80 typ.		0.03	1 typ.		
L4	0.60	1.00	0.023	0.039		
V2	0°	8°	0°	8°		

Figure 12. Footprint (dimensions in mm)



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Table 7. D²PAK dimensions

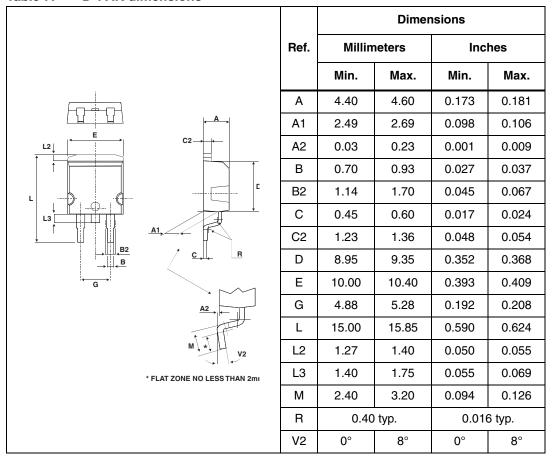
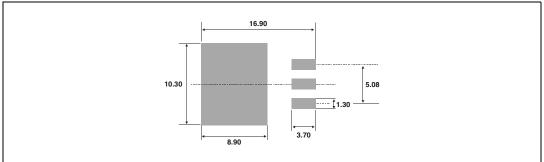


Figure 13. Footprint (dimensions in mm)



3 Ordering information

Table 8. Ordering information

Order code	Marking	Package	Weight	Base qty	Delivery mode	
STTH1002CBY-TR	STTH1002CY	DPAK	0.3 g	2500	Tape and reel	
STTH1002CGY-TR	STTH1002CGY	D ² PAK	1.48 g	1000	- Tape and reel	

4 Revision history

Table 9. Document revision history

Date	Revision	Changes	
21-Oct-2010	1	First issue.	
03-Nov-2011	2	Updated Table 7 and Table 8.	

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